# **74AUP1G58**

# Low-power configurable multiple function gate

Rev. 9 — 24 January 2022

**Product data sheet** 

## 1. General description

The 74AUP1G58 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{CC}$  or GND. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- ESD protection:
  - HBM JESD22-A114F exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G58GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2				
74AUP1G58GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G58GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP1G58GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1G58GX	-40 °C to +125 °C	X2SON6	plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 × 0.8 × 0.32 mm	SOT1255-2				



#### Low-power configurable multiple function gate

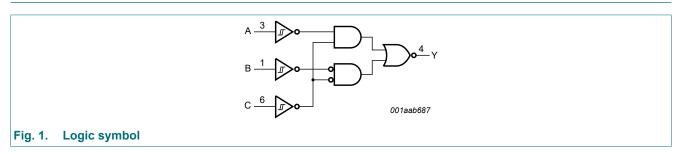
# 4. Marking

#### Table 2. Marking

Type number	Marking code [1]
74AUP1G58GW	аК
74AUP1G58GM	аК
74AUP1G58GN	аК
74AUP1G58GS	аК
74AUP1G58GX	аК

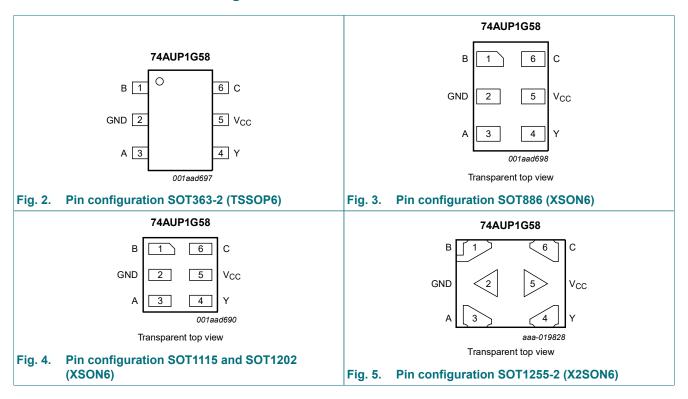
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1. Pinning



### Low-power configurable multiple function gate

# 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Υ	4	data output
V <sub>CC</sub>	5	supply voltage
С	6	data input

# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input			Output
С	В	A	Υ
L	L	L	L
L	L	Н	Н
L	Н	L	L
L	Н	Н	Н
Н	L	L	Н
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	L

## 7.1. Logic configurations

**Table 5. Function selection table** 

Logic function	Figure
2-input NAND	see Fig. 6
2-input NAND with both inputs inverted	see Fig. 9
2-input AND with inverted input	see Fig. 7 and Fig. 8
2-input NOR with inverted input	see Fig. 7 and Fig. 8
2-input OR	see Fig. 9
2-input OR with both inputs inverted	see Fig. 6
2-input XOR	see Fig. 10
Buffer	see Fig. 11
Inverter	see Fig. 12

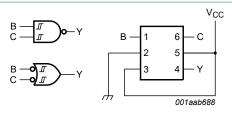


Fig. 6. 2-input NAND gate or 2-input OR with both inputs inverted

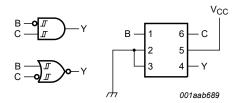


Fig. 7. 2-input AND gate with inverted B input or 2-input NOR gate with inverted C input

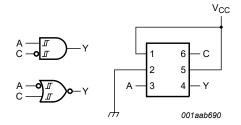


Fig. 8. 2-input AND gate with inverted C input or 2-input NOR gate with inverted A input

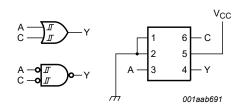


Fig. 9. 2-input OR gate or 2-input NAND gate with both inputs inverted

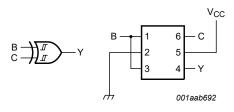


Fig. 10. 2-input XOR gate

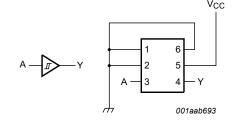


Fig. 11. Buffer

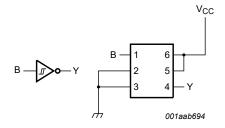


Fig. 12. Inverter

#### Low-power configurable multiple function gate

# 8. Limiting values

#### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	V <sub>O</sub> = 0 V to V <sub>CC</sub>	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C.

For SOT1255-2 (X2SON6) package: Ptot derates linearly with 3.3 mW/K above 75 °C.

## 9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

<sup>[2]</sup> For SOT363-2 (TSSOP6) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

## Low-power configurable multiple function gate

# 10. Static characteristics

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = 2$	25 °C					
V <sub>OH</sub>	HIGH-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
II	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
Cı	input capacitance	$V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.8	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C		1			-
V <sub>OH</sub>	HIGH-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.67	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_{O}$ = 2.7 mA; $V_{CC}$ = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V			±0.6	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>OH</sub>	HIGH-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μΑ
Δl <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ

# 11. Dynamic characteristics

## **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 14.

Symbol	Parameter	Conditions 25 °C		25 °C		25 °C -40 °C to +85 °C				°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max		
$C_L = 5 p$	F										
t <sub>pd</sub>	propagation	A, B and C to Y; see <u>Fig. 13</u> [2]									
	delay	V <sub>CC</sub> = 0.8 V	-	22.8	-	-	-	-	-	ns	
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	6.6	12.9	2.6	13.1	2.6	13.3	ns	
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.4	4.8	7.6	2.4	8.3	2.4	8.6	ns	
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	4.0	6.3	2.0	6.9	2.0	7.3	ns	
	V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	3.2	4.6	1.8	5.1	1.8	5.4	ns		
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	2.9	3.9	1.6	4.2	1.6	4.4	ns	

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Symbol	Parameter	Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Typ [1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 10	pF									
$t_{pd}$	propagation	A, B and C to Y; see Fig. 13 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	26.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	7.4	14.5	3.0	14.9	3.0	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.7	5.4	8.7	2.7	9.4	2.7	9.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.5	4.5	7.1	2.3	7.9	2.3	8.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.4	3.8	5.3	2.2	5.9	2.2	6.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.3	3.5	4.6	1.9	4.9	1.9	5.1	ns
C <sub>L</sub> = 15	pF		'	'		'	'		1	1
t <sub>pd</sub>	propagation	A, B and C to Y; see <u>Fig. 13</u> [2]								
·	delay	V <sub>CC</sub> = 0.8 V	-	29.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	8.3	16.1	3.3	16.7	3.3	17.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.9	9.7	3.0	10.5	3.0	11.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.8	5.0	7.9	2.5	8.7	2.5	9.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.2	5.9	2.5	6.6	2.5	6.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.5	3.9	5.2	2.2	5.5	2.2	5.8	ns
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	A, B and C to Y; see <u>Fig. 13</u> [2]								T
·	delay	V <sub>CC</sub> = 0.8 V	-	38.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.5	10.5	20.8	4.1	21.9	4.1	24.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.8	7.5	12.2	3.8	13.5	3.8	14.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.4	6.3	10.0	3.1	11.2	3.1	11.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.4	5.3	7.5	3.1	8.4	3.1	8.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.3	5.0	6.6	2.9	7.1	2.9	7.4	ns
C <sub>L</sub> = 5 p	F, 10 pF, 15 pF	and 30 pF								
C <sub>PD</sub>	power	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{CC}$ [3][4]								Т
. –	dissipation	V <sub>CC</sub> = 0.8 V	-	2.7	-	-	-	-	-	pF
	capacitance	V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
l		V <sub>CC</sub> = 1.4 V to 1.6 V	_	3.0	_	_	_	-	_	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.2	_	-	-	-	_	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	_	3.8	_	_	_	-	_	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.4	-	_	_	-	_	pF
		100 0.0 1 15 0.0 1								٦.

All typical values are measured at nominal V<sub>CC</sub>.

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\Sigma (C_L \times V_{CC}^{\ 2} \times f_o) = \text{sum of the outputs}.$ 

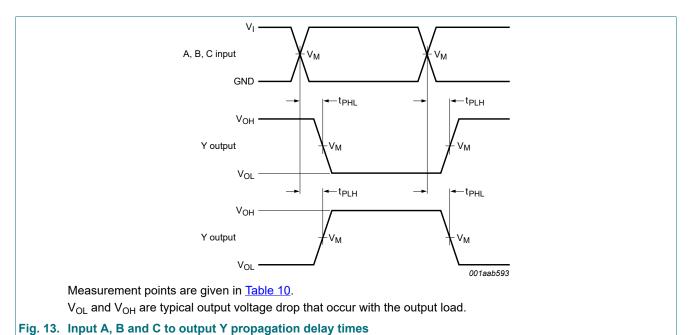
<sup>[1]</sup> [2]

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . All specified values are the average typical values over all stated loads.

<sup>[4]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

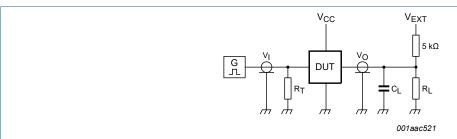
#### Low-power configurable multiple function gate

#### 11.1. Waveforms and test circuit



#### **Table 10. Measurement points**

Supply voltage	Output	Input				
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	$t_r = t_f$		
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns		



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator;

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 14. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ .

For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1  $M\Omega$ .

Low-power configurable multiple function gate

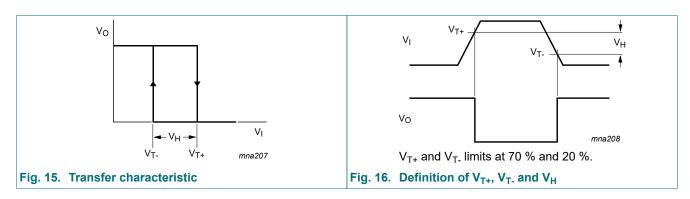
## 12. Transfer characteristics

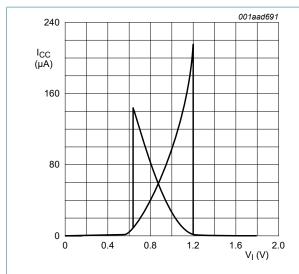
#### **Table 12. Transfer characteristics**

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 14.

Symbol	Parameter	r Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
	positive-going	see <u>Fig. 15</u> and <u>Fig. 16</u>								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V <sub>CC</sub> = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V <sub>CC</sub> = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V <sub>T-</sub>	negative-going	see Fig. 15 and Fig. 16								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
	Voltage	V <sub>CC</sub> = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V <sub>CC</sub> = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V <sub>H</sub> hysteresis voltage		(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 15</u> , <u>Fig. 16</u> , <u>Fig. 17</u> and <u>Fig. 18</u>								
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

### 12.1. Waveforms transfer characteristics





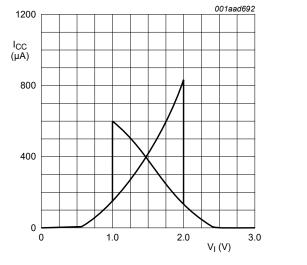


Fig. 17. Typical transfer characteristics;  $V_{CC} = 1.8 \text{ V}$ 

Fig. 18. Typical transfer characteristics;  $V_{CC} = 3.0 \text{ V}$ 

## Low-power configurable multiple function gate

# 13. Package outline

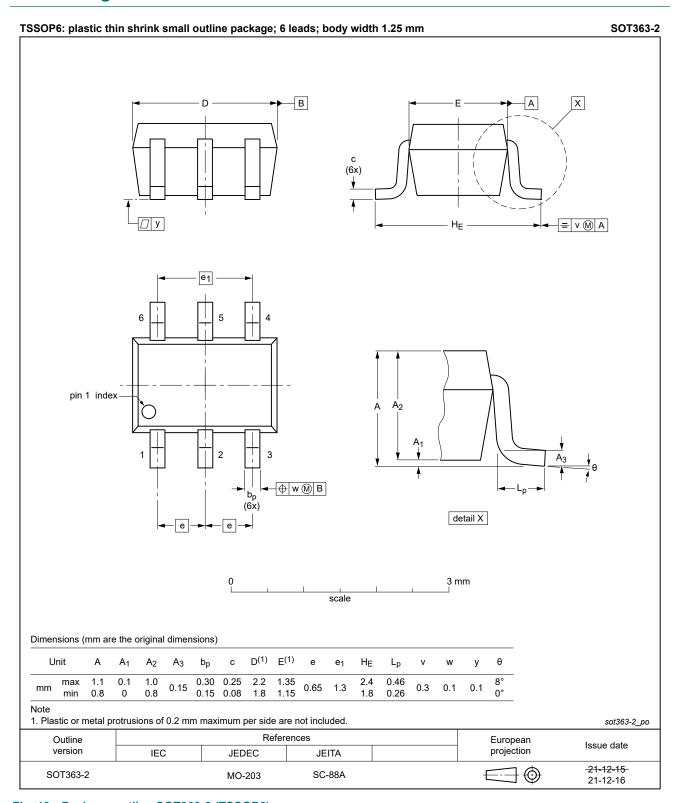


Fig. 19. Package outline SOT363-2 (TSSOP6)

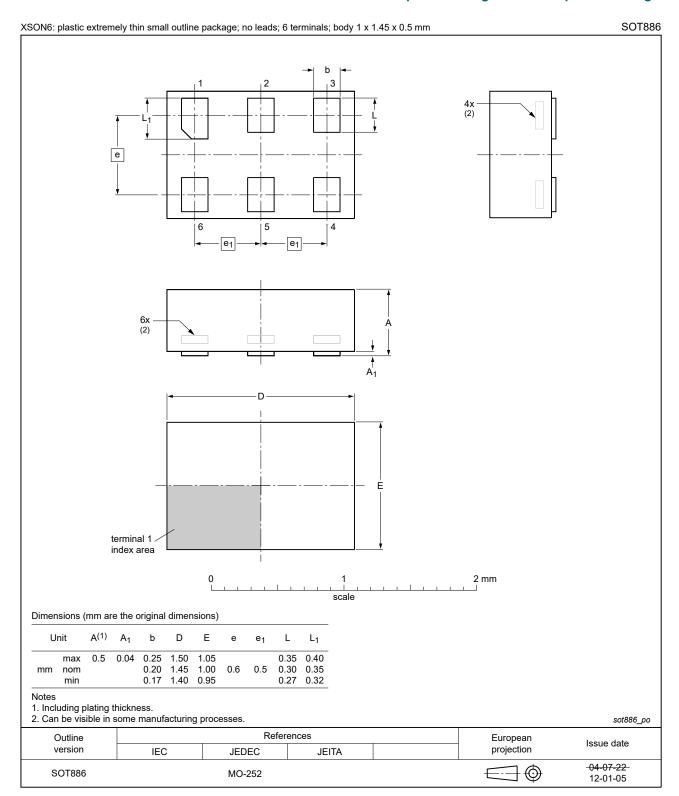


Fig. 20. Package outline SOT886 (XSON6)

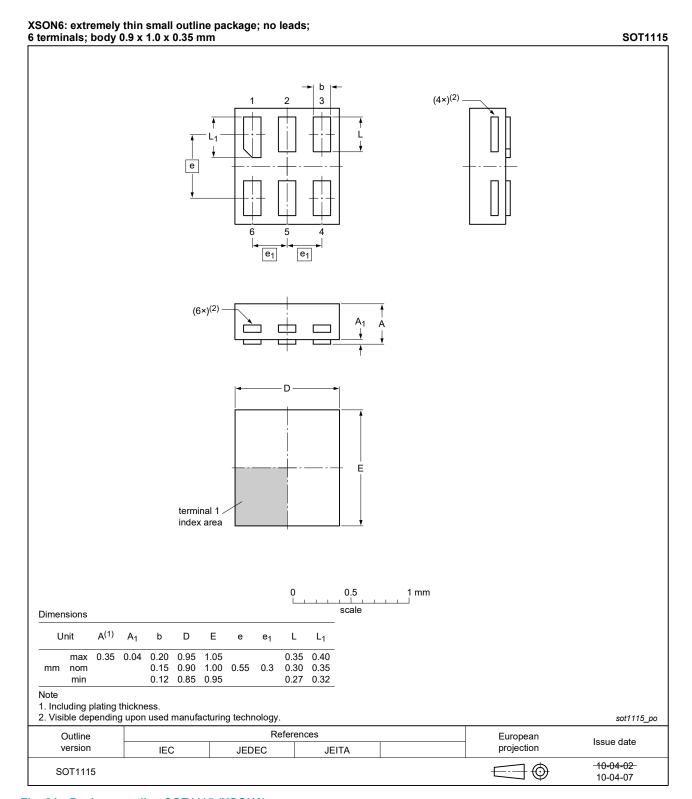


Fig. 21. Package outline SOT1115 (XSON6)

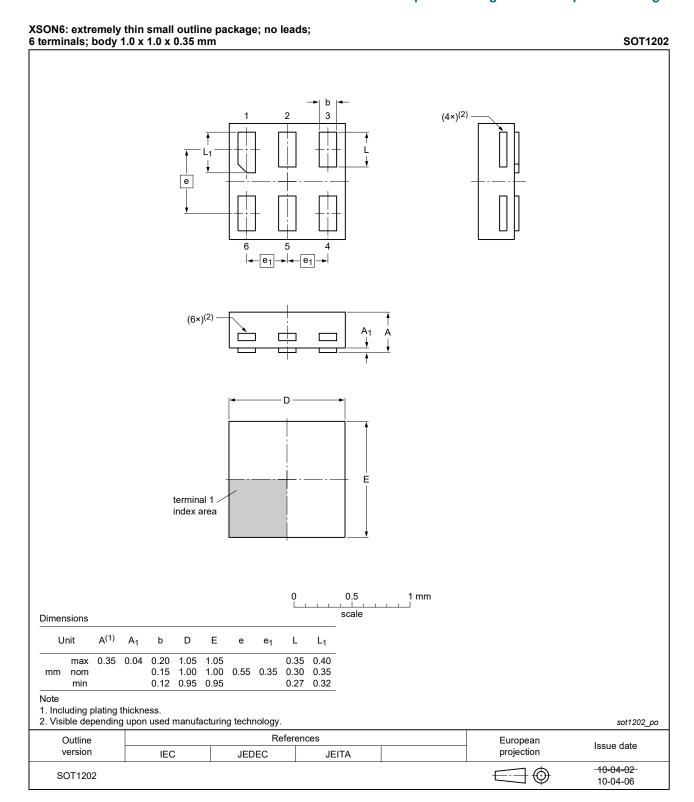


Fig. 22. Package outline SOT1202 (XSON6)

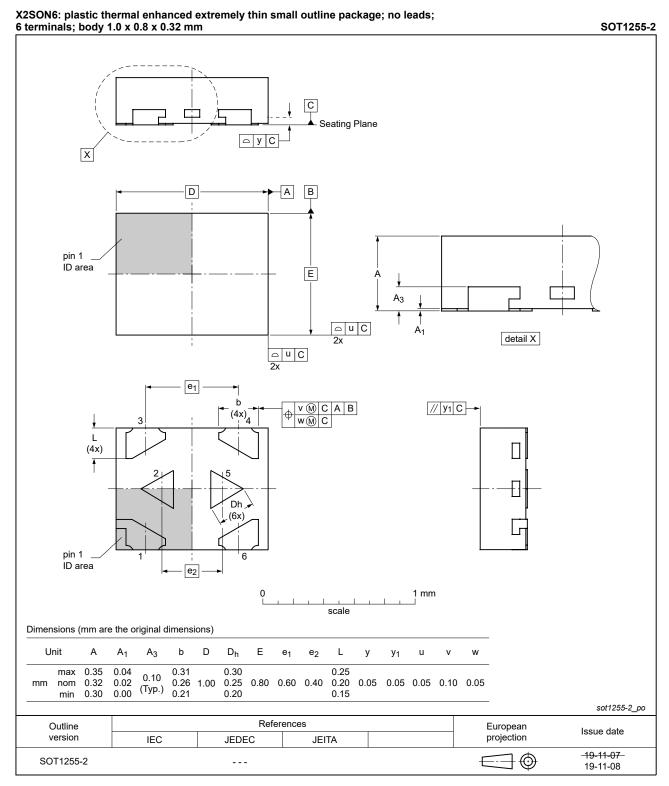


Fig. 23. Package outline SOT1255-2 (X2SON6)

## Low-power configurable multiple function gate

## 14. Abbreviations

#### **Table 13. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 15. Revision history

### **Table 14. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP1G58 v.9	20220124	Product data sheet	-	74AUP1G58 v.8				
Modifications:	• SOT363 (S	SOT363 (SC-88) package changed to SOT363-2 (TSSOP6) package.						
74AUP1G58 v.8	20210713	Product data sheet	-	74AUP1G58 v.7				
Modifications:	guidelines of Legal texts SOT1255 (X) Type number	SOT1255 (X2SON6) package changed to SOT1255-2 (X2SON6) package.  Type number 74AUP1G58GF (SOT891/XSON6) removed.  Section 1 and Section 2 updated.						
74AUP1G58 v.7	20150917	Product data sheet	_	74AUP1G58 v.6				
Modifications:	Added type	Added type number 74AUP1G58GX (SOT1255/X2SON6).						
74AUP1G58 v.6	20120815	Product data sheet	-	74AUP1G58 v.5				
Modifications:	Package out	Package outline drawing of SOT886 (Fig. 20) modified.						
74AUP1G58 v.5	20111129	Product data sheet	-	74AUP1G58 v.4				
74AUP1G58 v.4	20101011	Product data sheet	-	74AUP1G58 v.3				
74AUP1G58 v.3	20090622	Product data sheet	-	74AUP1G58 v.2				
74AUP1G58 v.2	20090326	Product data sheet	-	74AUP1G58 v.1				
74AUP1G58 v.1	20070131	Product data sheet	-	-				

## 16. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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